



桥式整流器 Bridge Rectifier

■特征 Features

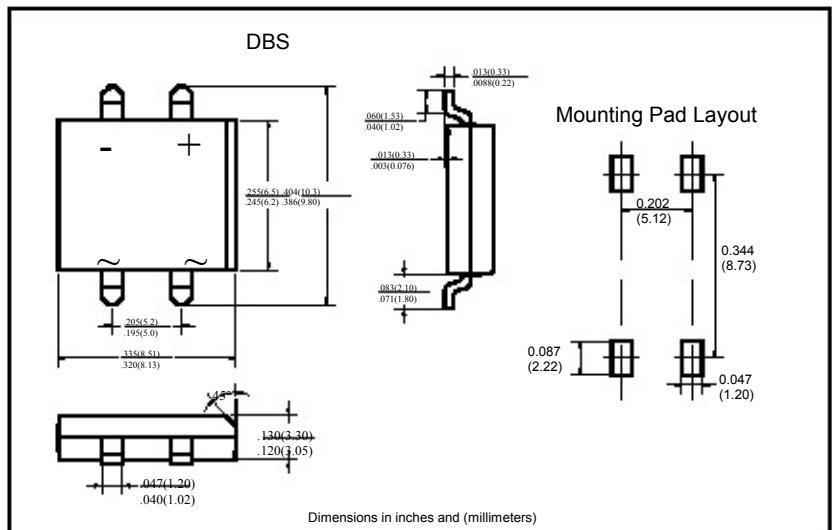
- I_o 1A
- V_{RRM} 50V~1000V
- 玻璃钝化芯片
Glass passivated chip
- 耐正向浪涌电流能力高
High surge forward current capability

■用途 Applications

- 作一般电源单相桥式整流用
General purpose 1 phase Bridge rectifier applications

■外形尺寸和印记

Outline Dimensions and Mark



■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

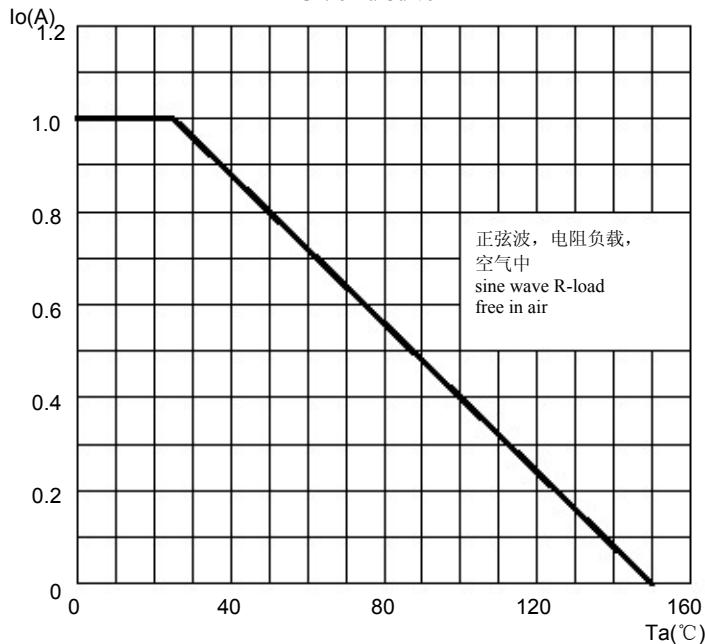
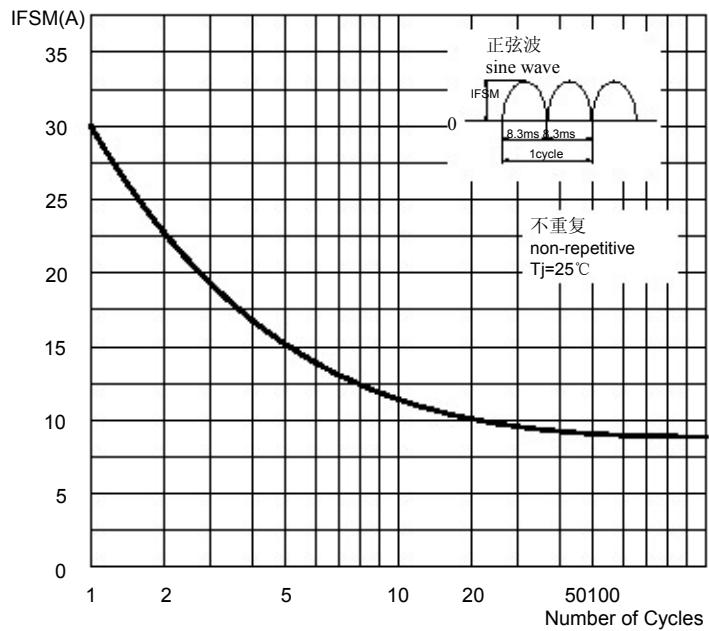
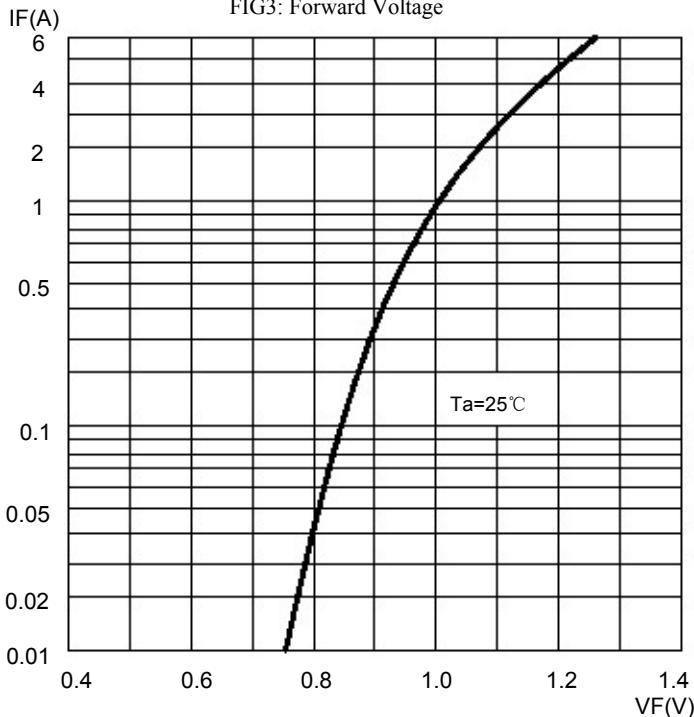
参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	DB1						
				01S	02S	03S	04S	05S	06S	07S
反向重复峰值电压 Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	400	600	800	1000
平均整流输出电流 Average Rectified Output Current	I_o	A	60Hz正弦波, 电阻负载, $T_a=25^\circ C$ 60Hz sine wave, R-load, $T_a=25^\circ C$	1						
正向(不重复)浪涌电流 Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz正弦波, 一个周期, $T_j=25^\circ C$ 60Hz sine wave, 1 cycle, $T_j=25^\circ C$	30						
正向浪涌电流的平方对电流 浪涌持续时间的积分值 Current Squared Time	I^2t	A^2S	1ms $\leq t < 8.3ms$ $T_j=25^\circ C$, 单个二极管 1ms $\leq t < 8.3ms$ $T_j=25^\circ C$, Rating of per diode	3.7						
存储温度 Storage Temperature	T_{stg}	°C		-55 ~ +150						
结温 Junction Temperature	T_j	°C		-55 ~ +150						

■电特性 ($T_a=25^\circ C$ 除非另有规定)Electrical Characteristics ($T_a=25^\circ C$ Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition	最大值 Max
正向峰值电压 Peak Forward Voltage	V_{FM}	V	$I_{FM}=0.5A$, 脉冲测试, 单个二极管的额定值 $I_{FM}=0.5A$, Pulse measurement, Rating of per diode	1.05
反向峰值电流 Peak Reverse Current	I_{RRM}	μA	$V_{RM}=V_{RRM}$, 脉冲测试, 单个二极管的额定值 $V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	10
热阻 Thermal Resistance	R_{0J-A}	°C/W	结和环境之间, 安装在玻璃-环氧基板上 Between junction and ambient, On glass-epoxy substrate	68
	R_{0J-L}		结和引线之间 Between junction and lead	15



■特性曲线 (典型) Characteristics(Typical)

图1: Io-Ta曲线
FIG1:Io-Ta Curve图2: 耐正向浪涌电流曲线
FIG2:Surge Forward Current Capability图3: 正向电压曲线
FIG3: Forward Voltage图4: 反向电流曲线
FIG4:Typical Reverse Characteristics